Phototransistors

Panasonic

PNZ109CL (PN109CL)

Silicon planar type

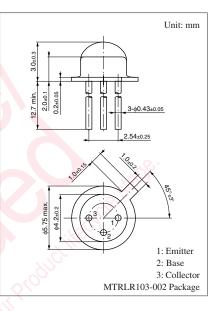
For optical control systems

Features

- High sensitivity: $I_{CE(L)} = 2 \text{ mA (min.)}$
- Wide directivity characteristics for easy use
- Fast response: $t_r = 5 \ \mu s \ (typ.)$
- Signal mixing capability using base pin
- Small size (low in height) package
- Resin to cutoff visible light is used

Absolute Maximum Ratings $T_a = 25^{\circ}C$

	- d		
Parameter	Symbol	Rating	Unit
Collector-emitter voltage (Base open)	V _{CEO}	20	V
Collector-base voltage (Emitter open)	V _{CBO}	30	v
Emitter-collector voltage (Base open)	V _{ECO}	3	V
Emitter-base voltage (Collector open)	V _{EBO}	5	V
Collector current	I _C	20	mA
Collector power dissipation *	P _C	100	mW
Operating ambient temperature	T _{opr}	-25 to +85	°C
Storage temperature	T _{stg}	-30 to +100	°C ₀
		24	



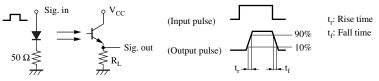
Electrical-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Photocurrent *1	I _{CE(L)}	$V_{CE} = 10 \text{ V}, \text{ L} = 500 \text{ lx}$	2.5	4.0		mA
Dark current	I _{CEO}	V _{CE} = 10 V	3	0.05	2.00	μΑ
Peak emission wavelength	λ_{p}	V _{CE} = 10 V	Q.X	900		nm
Half-power angle	θ	The angle from which photocurrent becomes 50%		80		0
Rise time *2	t _r	$V_{CC} = 10 \text{ V}, \text{ I}_{CE(L)} = 5 \text{ mA}, \text{ R}_{L} = 100 \Omega$		5		μs
Fall time *2	t _f	ist wh		6		μs
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_{CE(L)} = 1 \text{ mA}, L = 1000 \text{ lx}$		0.3	0.6	V

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. Spectral sensitivity characteristics: Sensitivity for wave length over 400 nm maximum sensitivity ratio is 100%.

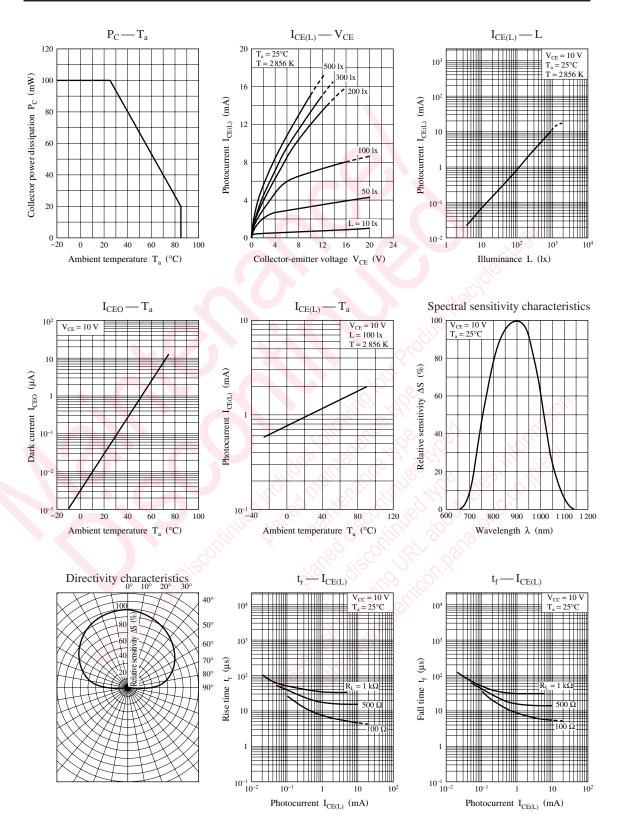
- 3. This device is designed be disregarded radiation.
- 4. *1: Source: Tungsten (color temperature 2856 K)
 - *2: Switching time measurement circuit



Note) The part number in the parenthesis shows conventional part number.

PNZ109CL





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